WHAT IS CLAIMED IS:

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- 1. An organic EL panel having a plurality of organic EL elements arranged in a matrix, comprising:
- a drive transistor provided to each of the plurality of organic EL elements, for controlling a drive current to be supplied to a corresponding organic EL element; and
 - a peripheral transistor provided near the periphery of a display area where the plurality of organic EL elements are arranged, for outputting a signal for controlling the drive transistor, wherein
 - a gate length of the drive transistor is set longer than a gate length of the peripheral transistor.
- 15 2. The organic EL panel according to claim 1, wherein the gate length of the peripheral transistor is set to a value between 1 and 10 $\mu m\,.$
- 3. The organic EL panel according to claim 1, wherein the gate length of the drive transistor is set to a value between 10 and 100 μm .
- 4. The organic EL panel according to claim 1, wherein a gate width of the drive transistor and a gate width of the25 peripheral transistor are set to the same value.
 - 5. An organic EL panel having a plurality of organic EL elements

arranged in a matrix, comprising:

- a drive transistor provided to each of the plurality of organic EL elements, for controlling a drive current to be supplied to a corresponding organic EL element; and
- a peripheral transistor provided near the periphery of a display area where the plurality of organic EL elements are arranged, for outputting a signal for controlling the drive transistor, wherein

(a gate length L)/(a gate width W) of the drive transistor $10 \quad \text{is set larger than (a gate length L)/(a gate width W) of the peripheral transistor. }$

- 6. The organic EL panel according to claim 5, wherein the gate length of the peripheral transistor is set to a value 15 between 1 and 10 μm .
 - 7. The organic EL panel according to claim 5, wherein the gate length of the drive transistor is set to a value between 10 and 100 μm_{\odot}

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- 8. The organic EL panel according to claim 5, wherein the gate width of the peripheral transistor is set to a value between 5 and 500 $\mu m\,.$
- 25 9. The organic EL panel according to claim 5, wherein the gate width of the drive transistor is set to a value between 5 and 10 μm .